Inverter

# **HITACHI**

ADE-205-303B (Z) 3rd. Edition April 2001

#### **Description**

The HD74HCT1G04 is high speed CMOS inverter using silicon gate CMOS process. With CMOS low power dissipation, it provides high speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output.

#### **Features**

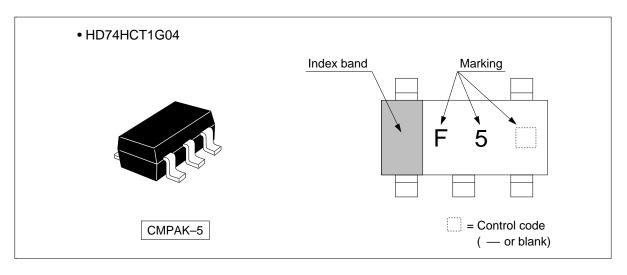
- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- TTL compatible input level.

Supply voltage range: 4.5 to 5.5 V

Operating temperature range: -40 to +85°C

•  $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$ 

#### **Outline and Article Indication**



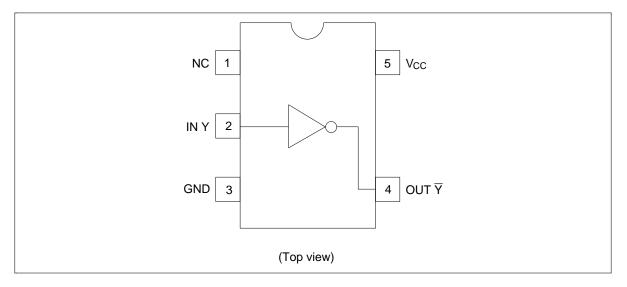


## **Function Table**

Input A	Output Y				
Н	L				
L	Н				

H : High level L : Low level

# Pin Arrangement



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V <sub>cc</sub>	-0.5 to 7.0	V	
Input voltage range *1	V <sub>I</sub>	$-0.5$ to $V_{cc}$ + 0.5	V	
Output voltage range *1, 2	Vo	$-0.5$ to $V_{cc}$ + 0.5	V	Output : H or L
Input clamp current	I <sub>IK</sub>	±20	mA	$V_i < 0 \text{ or } V_i > V_{CC}$
Output clamp current	I <sub>OK</sub>	±20	mA	$V_{o} < 0 \text{ or } V_{o} > V_{cc}$
Continuous output current	Io	±25	mA	$V_{\rm o} = 0$ to $V_{\rm cc}$
$\begin{tabular}{ll} \hline Continuous current through \\ V_{cc} \ or \ GND \\ \hline \end{tabular}$	I <sub>CC</sub> or I <sub>GND</sub>	±25	mA	
Maximum power dissipation at Ta = 25°C (in still air) *3	P <sub>T</sub>	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

#### Notes:

- The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was caluculated using a junction temperature of 150°C.

## **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	<b>Test Conditions</b>
Supply voltage range	$V_{cc}$	4.5	5.5	V	
Input voltage range	V <sub>I</sub>	0	5.5	V	
Output voltage range	Vo	0	V <sub>cc</sub>	V	
Output current	I <sub>OL</sub>	_	2	mA	V <sub>CC</sub> = 4.5 to 5.5 V
	I <sub>OH</sub>	_	-2	_	$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Input rise / fall time (0.3 V to 2.7 V)	t <sub>r</sub> , t <sub>f</sub>	0	500	ns	$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
Operating temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

## **Electrical Characteristics**

Item	Symbol	$\mathbf{V}_{cc}$	$T_a = 2$	5°C		$T_a = -40 \text{ to } 85^{\circ}\text{C}$		$T_a = -40 \text{ to } 85^{\circ}\text{C}$ Unit		Test Conditions		
		(V)	Min	Тур	Max	Min	Max	='				
Input voltage	$V_{IH}$	4.5 to 5.5	2.0	_	_	2.0	_	V				
	V <sub>IL</sub>	4.5 to 5.5		_	0.8	_	0.8	_				
Output voltage	V <sub>OH</sub>	4.5	4.4	4.5	_	4.4	_	V	$V_{IN} = V_{IL}$	$I_{OH} = -20 \mu A$		
		4.5	4.18	4.31	_	4.13	_			$I_{OH} = -2 \text{ mA}$		
	$V_{\text{OL}}$	4.5		0.0	0.1	_	0.1	_	$V_{\scriptscriptstyle IN}=V_{\scriptscriptstyle IH}$	$I_{OL} = 20 \mu A$		
		4.5	_	0.17	0.26	_	0.33			$I_{OL} = 2 \text{ mA}$		
Input current	I <sub>IN</sub>	5.5	_	_	±0.1	_	±1.0	μΑ	$V_{IN} = V_{CC} c$	or GND		
Operating current	I <sub>cc</sub>	5.5	_	_	1.0	_	10.0	μΑ	$V_{IN} = V_{CC}$	or GND		
Quiescent supply current	I <sub>CCT</sub>	5.5	_	_	2.0		2.9	mA	One input $V_{IN} = 2.4 \text{ V}$ , other input $V_{CC}$ or GND			

## **Switching Characteristics**

Item	Symbol	$T_a = 25^{\circ}$	C		Unit	<b>Test Conditions</b>		
		Min	Тур	Max				
Output rise / fall time	t <sub>TLH</sub> t <sub>THL</sub>	_	6	10	ns	Test circuit		
Propagation delay time	t <sub>PLH</sub>		7.5	12	ns	Test circuit		
	t <sub>PHL</sub>	_	10	17				

 $(C_L = 15 \text{ pF}, t_r = t_f = 6 \text{ ns}, V_{CC} = 5 \text{ V})$ 

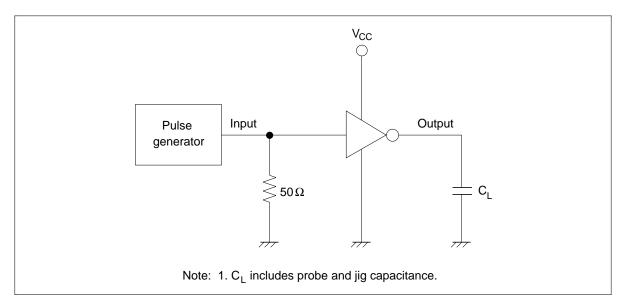
Item	Symbol		$T_a = 25^{\circ}C$		$T_a = -40 \text{ to } 85^{\circ}\text{C}$		Unit	<b>Test Conditions</b>	
		$\mathbf{V}_{\mathrm{cc}}$	Min	Тур	Max	Min	Max	_	
Output rise / fall time	t <sub>TLH</sub> t <sub>THL</sub>	4.5	_	14	25	_	31	ns	Test circuit
Propagation delay time	t <sub>PLH</sub>	4.5	_	11.2	16	_	20	ns	Test circuit
	t <sub>PHL</sub>	4.5	_	16.4	27	_	31	_	
Input capacitance	C <sub>IN</sub>	_	_	2.5	5	_	5	pF	
Equivalent capacitance	C <sub>PD</sub>	_	_	10	_	_	_	pF	

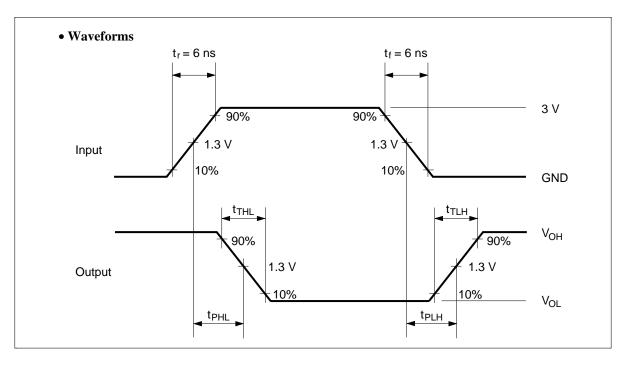
 $(C_L = 50 \text{ pF}, t_r = t_f = 6 \text{ ns})$ 

Note: C<sub>PD</sub> is equivalent capacitance inside of the IC calculated from the operating current without load (see test circuit). The average operating current without load is calculated according to the expression below.

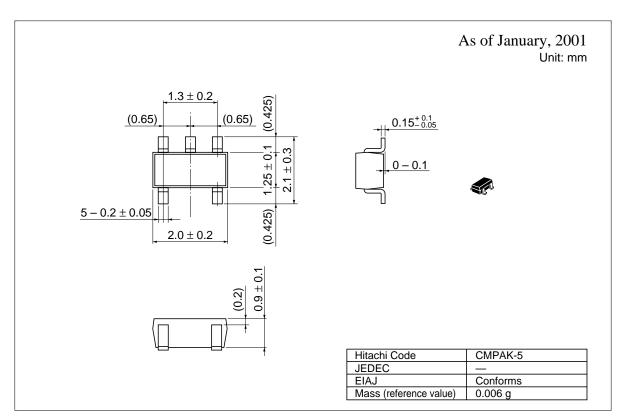
 $I_{CC}$  (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

## **Test Circuit**





## **Package Dimensions**



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